

Ordering number:EN3024

PNP/NPN Epitaxial Planar Silicon Transistors

**2SA1704/2SC4484****High-Current Driver Applications****Applications**

- Voltage regulators, relay drivers, lamp drivers.

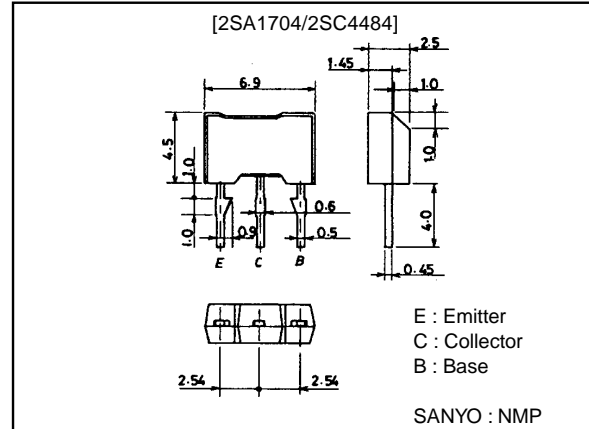
**Features**

- Adoption of FBET, MBIT processes.
- Low collector-to-emitter voltage.
- Large current capacity and wide ASO.
- Fast switching speed.

**Package Dimensions**

unit:mm

2064



() : 2SA1704

**Specifications****Absolute Maximum Ratings at Ta = 25°C**

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	$V_{CBO}$		(-)30	V
Collector-to-Emitter Voltage	$V_{CEO}$		(-)25	V
Emitter-to-Base Voltage	$V_{EBO}$		(-)6	V
Collector Current	$I_C$		(-)2.5	A
Collector Current (Pulse)	$I_{CP}$		(-)5	A
Collector Dissipation	$P_C$		1	W
Junction Temperature	$T_J$		150	°C
Storage Temperature	$T_{stg}$		-55 to +150	°C

**Electrical Characteristics at Ta = 25°C**

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector Cutoff Current	$I_{CBO}$	$V_{CB}=(-)50V, I_E=0$			(-)100	nA
Emitter Cutoff Current	$I_{EBO}$	$V_{EB}=(-)4V, I_C=0$			(-)100	nA
DC Current Gain	$h_{FE1}$	$V_{CE}=(-)2V, I_C=(-)100mA$	100*		400*	
	$h_{FE2}$	$V_{CE}=(-)2V, I_C=(-)1A$	65			
Gain-Bandwidth Product	$f_T$	$V_{CE}=(-)10V, I_C=(-)50mA$		150		MHz

\* : The 2SA1704/2SC4484 are classified by 100mA  $h_{FE}$  as follows :

100 R 200	140 S 280	200 T 400
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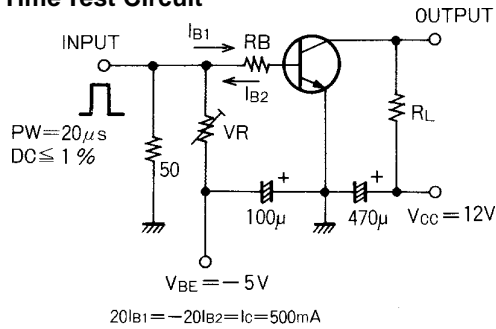
TOKYO OFFICE Tokyo Bldg., 1-10, 1 Chome, Ueno, Taito-ku, TOKYO, 110-8534 JAPAN

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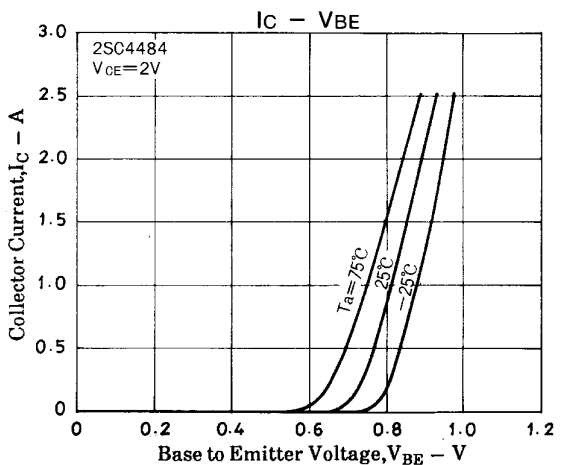
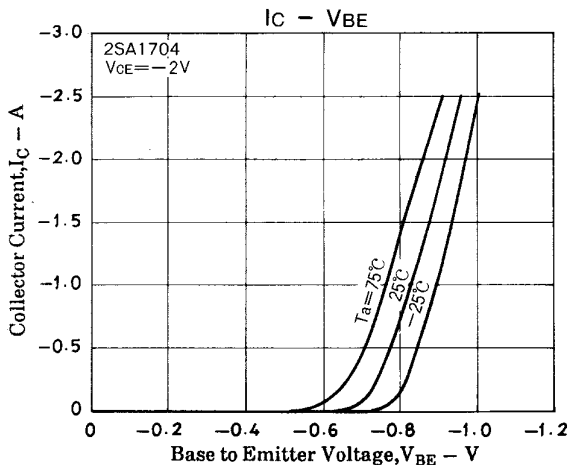
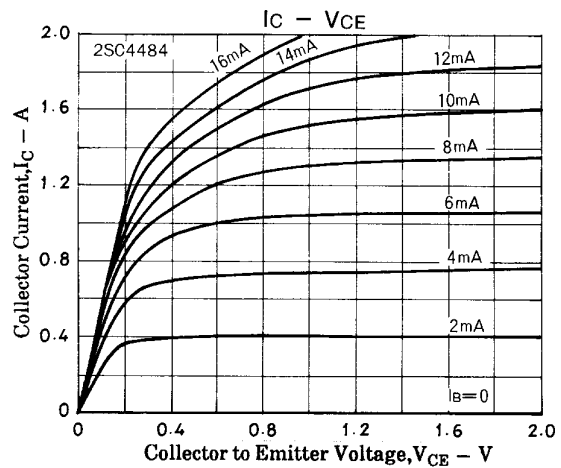
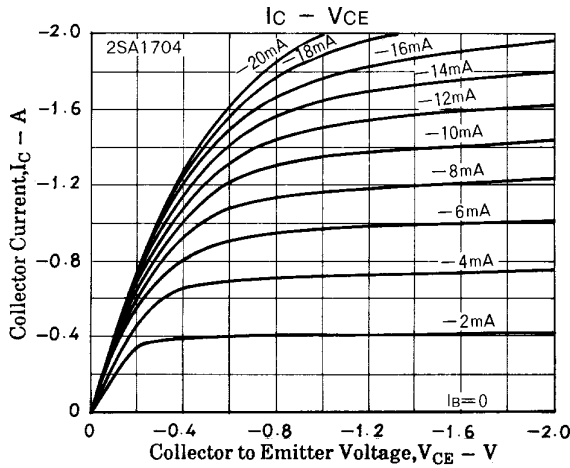
# 2SA1704/2SC4484

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector-to-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C=(-)1.5A, I_B=(-)75mA$		(-0.35)	(-0.6)	V
Base-to-Emitter Saturation Voltage	$V_{BE(sat)}$	$I_C=(-)1.5A, I_B=(-)75mA$		(-0.95)	(-1.2)	V
Output Capacitance	$C_{ob}$	$V_{CB}=(-)10V, f=1MHz$		(32)19		pF
Collector-to-Base Breakdown Voltage	$V_{(BR)CBO}$	$I_C=(-)10\mu A, I_E=0$	(-30)			V
Collector-to-Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C=(-)1mA, R_{BE}=\infty$	(-25)			V
Emitter-to-Base Breakdown Voltage	$V_{(BR)EBO}$	$I_E=(-)10\mu A, I_C=0$	(-6)			V
Turn-ON Time	$t_{on}$	See specified Test Circuit		60		ns
Storage Time	$t_{stg}$	See specified Test Circuit		(350)		ns
				500		ns
Fall Time	$t_f$	See specified Test Circuit		25		ns

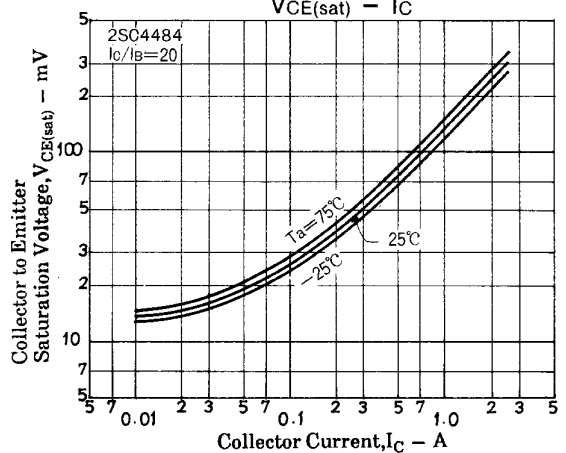
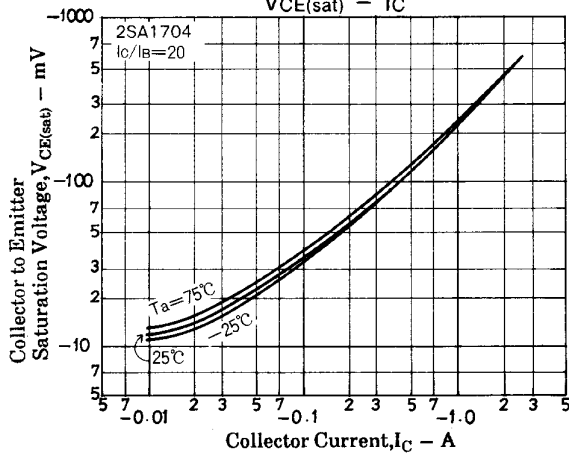
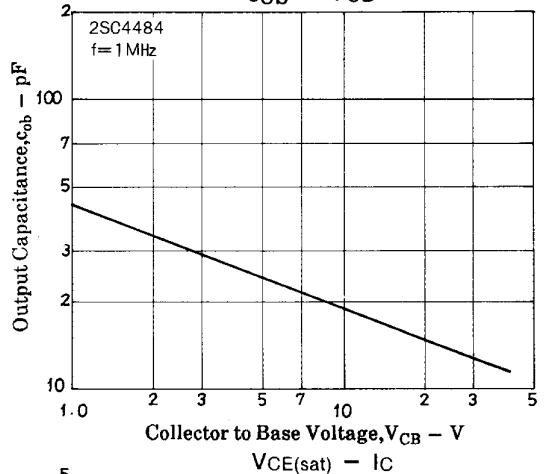
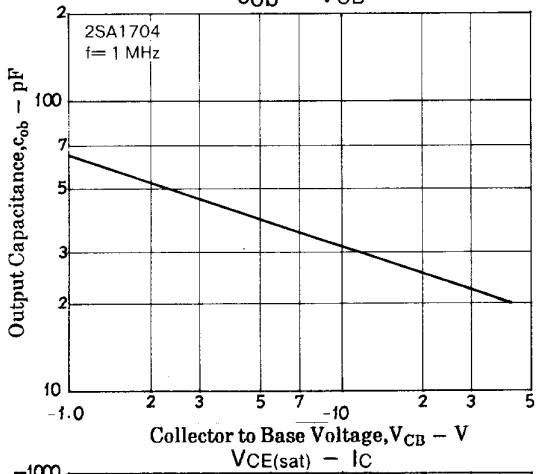
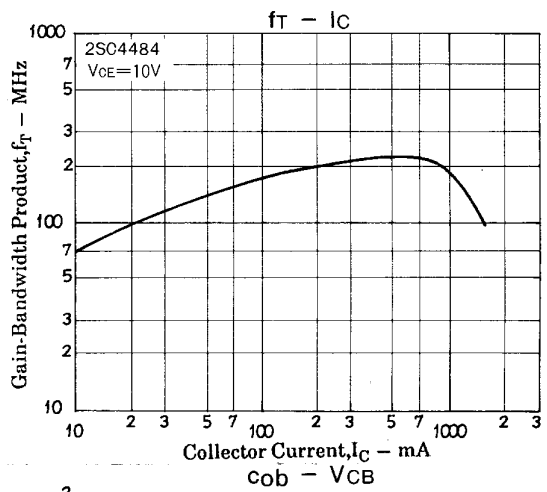
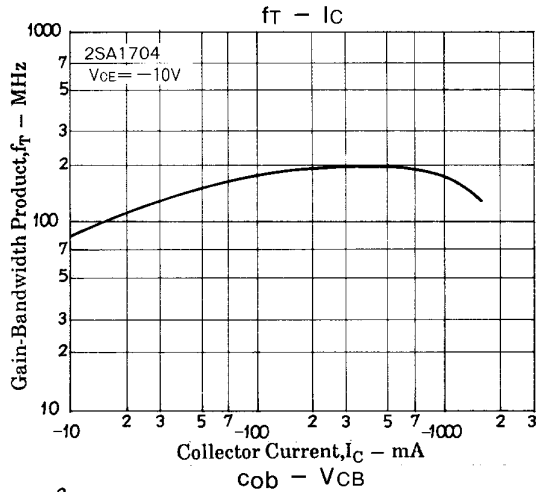
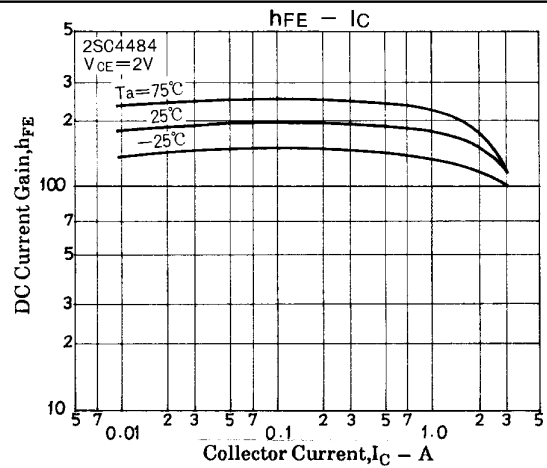
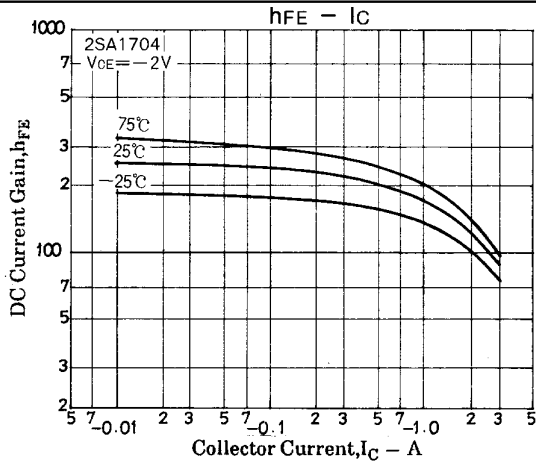
## Switching Time Test Circuit



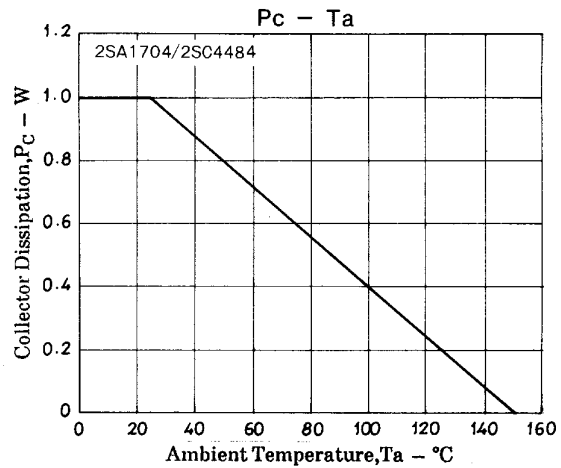
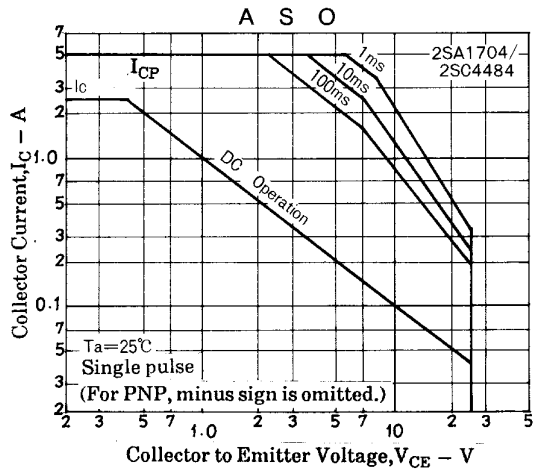
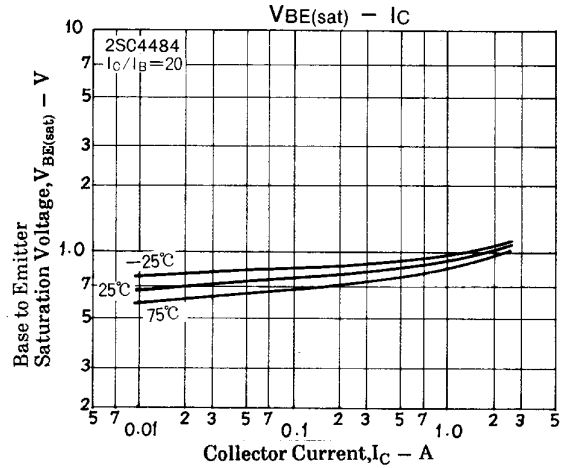
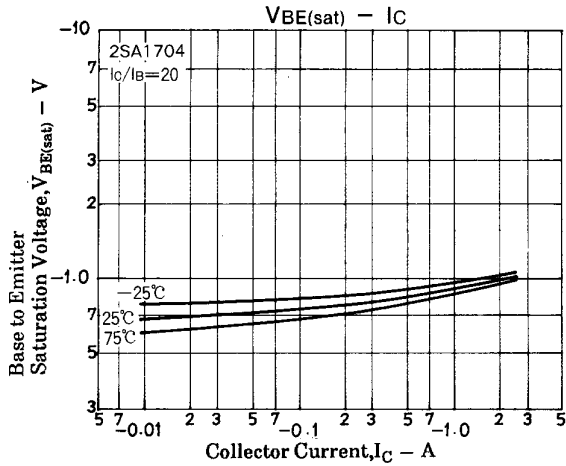
(For PNP, the polarity is reversed.)  
Unit (resistance : Ω, capacitance : F)



# 2SA1704/2SC4484



## 2SA1704/2SC4484



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